### Advanced Micro Devices

### PAL16R8 Family

#### 20-Pin TTL Programmable Array Logic

#### DISTINCTIVE CHARACTERISTICS

- As fast as 4.5 ns maximum propagation delay
- Popular 20-pin architectures: 16L8, 16R8, 16R6, 16R4
- Programmable replacement for high-speed TTL logic
- Register preload for testability

- Power-up reset for initialization
- Extensive third-party software and programmer support through FusionPLD partners
- 20-Pin DIP and PLCC packages save space
- 28-Pin PLCC-4 package provides ultra-clean high-speed signals

#### **GENERAL DESCRIPTION**

The PAL16R8 Family (PAL16L8, PAL16R8, PAL16R6, PAL16R4) includes the PAL16R8-5/4 Series which provides the highest speed in the 20-pin TTL PAL device family, making the series ideal for high-performance applications. The PAL16R8 Family is provided with standard 20-pin DIP and PLCC pinouts and a 28-pin PLCC pinout. The 28-pin PLCC pinout contains seven extra ground pins interleaved between the outputs to reduce noise and increase speed.

The devices provide user-programmable logic for replacing conventional SSI/MSI gates and flip-flops at a reduced chip count.

The family allows the systems engineer to implement the design on-chip, by opening fuse links to configure AND and OR gates within the device, according to the desired logic function. Complex interconnections between gates, which previously required time-consuming layout, are lifted from the PC board and placed on silicon, where they can be easily modified during prototyping or production.

The PAL device implements the familiar Boolean logic transfer function, the sum of products. The PAL device is a programmable AND array driving a fixed OR array.

The AND array is programmed to create custom product terms, while the OR array sums selected terms at the outputs.

In addition, the PAL device provides the following options:

- Variable input/output pin ratio
- Programmable three-state outputs
- Registers with feedback

Product terms with all connections opened assume the logical HIGH state; product terms connected to both true and complement of any single input assume the logical LOW state. Registers consist of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock. Unused input pins should be tied to Vcc or GND.

The entire PAL device family is supported by the FusionPLD partners. The PAL family is programmed on conventional PAL device programmers with appropriate personality and socket adapter modules. Once the PAL device is programmed and verified, an additional connection may be opened to prevent pattern readout. This feature secures proprietary circuits.

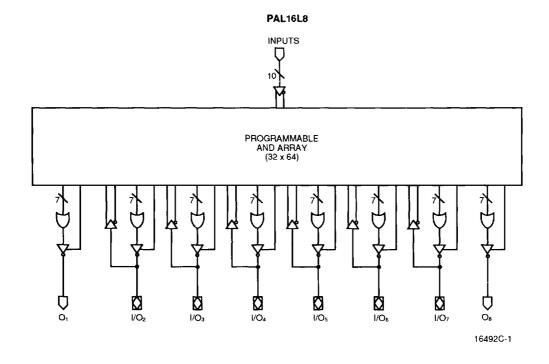
#### PRODUCT SELECTOR GUIDE

Device	Dedicated Inputs	Outputs	Product Terms/ Output	Feedback	Enable
PAL16L8	10	6 comb. 2 comb.	7 7	I/O 	prog. prog.
PAL16R8	8	8 reg.	8	reg.	pin
PAL16R6	8	6 reg. 2 comb.	 8 7	reg. I/O	pin prog.
PAL16R4	8	4 reg. 4 comb.		reg. I/O	pin prog.

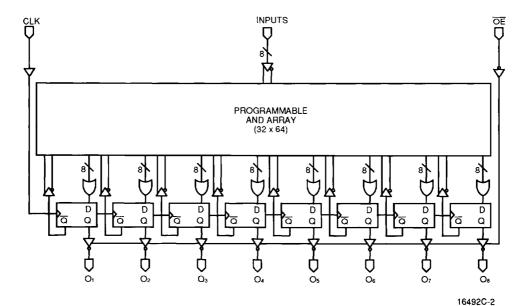
Publication# 16492 Rev. C Amendment/0 Issue Date: October 1994

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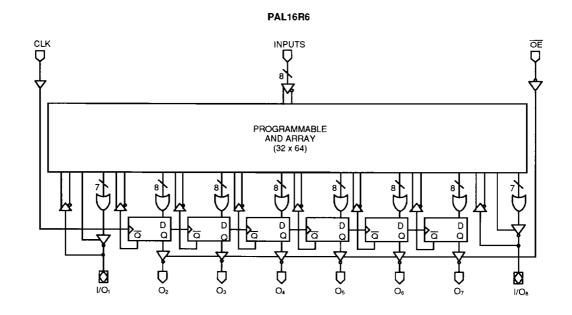
#### **BLOCK DIAGRAMS**



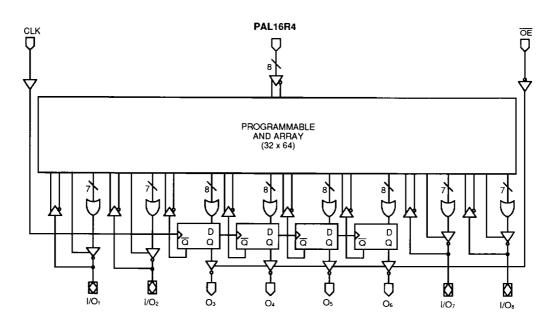
#### PAL16R8



#### **BLOCK DIAGRAMS**



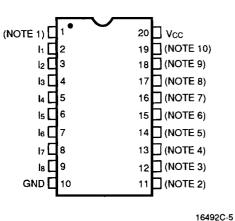
16492C-3



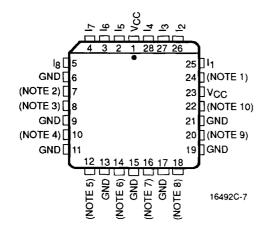
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### CONNECTION DIAGRAMS

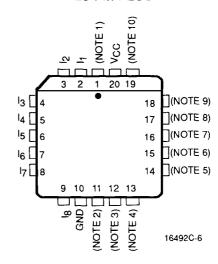




#### 28-Pin PLCC



#### 20-Pin PLCC



#### **PIN DESIGNATIONS**

CLK = Clock
GND = Ground
I = Input
I/O = Input/Output
O = Output
OE = Output Enable
Vcc = Supply Voltage

#### Note:

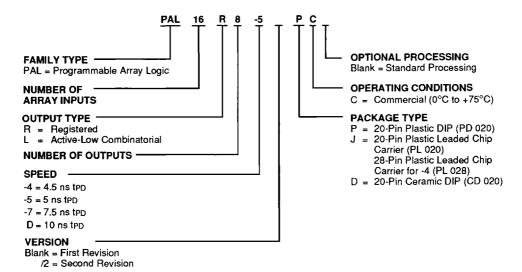
Pin 1 is marked for orientation.

Note	16L8	16R8	16R6	16R4
1	lo	CLK	CLK	CLK
2	l9	ŌĒ	ŌĒ	ŌĒ
3	O <sub>1</sub>	O <sub>1</sub>	I/O <sub>1</sub>	I/O <sub>1</sub>
4	I/O <sub>2</sub>	O <sub>2</sub>	O <sub>2</sub>	I/O <sub>2</sub>
5	I/O <sub>3</sub>	O <sub>3</sub>	Оз	O <sub>3</sub>
- 6	1/04	O <sub>4</sub>	O <sub>4</sub>	O <sub>4</sub>
7	I/O <sub>5</sub>	O <sub>5</sub>	O <sub>5</sub>	O <sub>5</sub>
8	I/O <sub>6</sub>	O <sub>6</sub>	O <sub>6</sub>	O <sub>6</sub>
9	I/O <sub>7</sub>	O <sub>7</sub>	O <sub>7</sub>	I/O <sub>7</sub>
10	O <sub>8</sub>	O <sub>8</sub>	I/O <sub>8</sub>	I/O <sub>B</sub>



# ORDERING INFORMATION Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



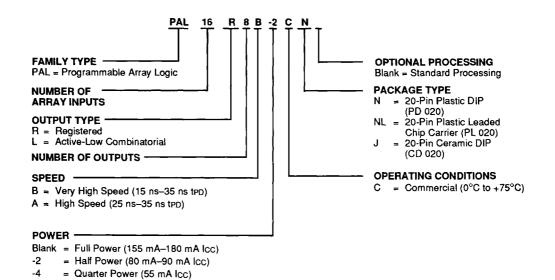
Valid Combinations					
PAL16L8					
PAL16R8	5D0 510 410				
PAL16R6	-5PC, -5JC, -4JC				
PAL16R4					
PAL16L8-7					
PAL16R8-7	PC, JC, DC				
PAL16R6-7	. 5,50,50				
PAL16R4-7					
PAL16L8D/2					
PAL16R8D/2	PC, JC				
PAL16R6D/2	. 5,00				
PAL16R4D/2					

#### Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

# ORDERING INFORMATION Commercial Products (MMI Marking Only)

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
PAL16L8						
PAL16R8	R R-2 A					
PAL16R6	B, B-2, A, B-4	CN, CNL, CJ				
PAL16R4						

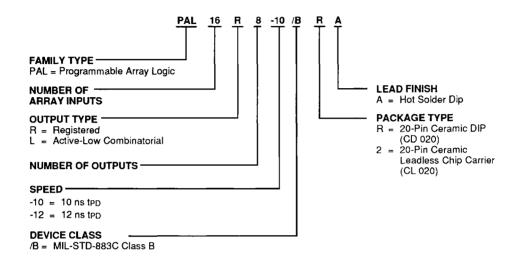
#### **Valid Combinations**

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Note: Marked with MMI logo.

# ORDERING INFORMATION APL Products

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations					
PAL16L8					
PAL16R8	10 10	(BDA (BAA			
PAL16R6	-10, -12	/BRA, /B2A			
PAL16R4					

#### **Valid Combinations**

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

#### Military Burn-In

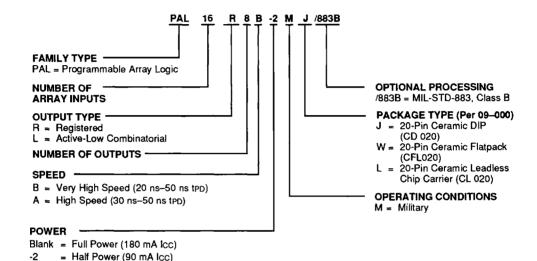
Military burn-in is in accordance with the current revision of MiL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

#### **Group A Tests**

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

# ORDERING INFORMATION APL Products (MMI Marking Only)

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations					
PAL16L8					
PAL16R8	] <sub>B.</sub>	MJ/883B,			
PAL16R6	B-2, A. B-4	MW/883B, ML/883B			
PAL16R4	] '', 5				

= Quarter Power (55 mA Icc)

### Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Note: Marked with MMI logo.

#### Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

#### **Group A Tests**

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

#### **FUNCTIONAL DESCRIPTION**

#### Standard 20-Pin PAL Family

The standard bipolar 20-pin PAL family devices have common electrical characteristics and programming procedures. Four different devices are available, including both registered and combinatorial devices. All parts are produced with a fuse link at each input to the AND gate array, and connections may be selectively removed by applying appropriate voltages to the circuit. Utilizing an easily-implemented programming algorithm, these products can be rapidly programmed to any customized pattern. Extra test words are preprogrammed during manufacturing to ensure extremely high field programming yields, and provide extra test paths to achieve excellent parametric correlation.

#### **Pinouts**

The PAL16R8 Family is available in the standard 20-pin DIP and PLCC pinouts and the PAL16R8-4 Series is available in the new 28-pin PLCC pinout. The 28-pin PLCC pinout gives the designer the cleanest possible signal with only 4.5 ns delay.

The PAL16R8-4 pinout has been designed to minimize the noise that can be generated by high-speed signals. Because of its inherently shorter leads, the PLCC package is the best package for use in high-speed designs. The short leads and multiple ground signals reduce the effective lead inductance, minimizing ground bounce. Placing the ground pins between the outputs optimizes the ground bounce protection, and also isolates the outputs from each other, eliminating cross-talk. This pinout can reduce the effective propagation delay by as much as 20% from a standard DIP pinout. Design files for PAL16R8-4 Series devices are written as if the device had a standard 20-pin DIP pinout for most design software packages.

#### Variable Input/Output Pin Ratio

The registered devices have eight dedicated input lines, and each combinatorial output is an I/O pin. The PAL16L8 has ten dedicated input lines and six of the eight combinatorial outputs are I/O pins. Buffers for device inputs have complementary outputs to provide user-programmable input signal polarity. Unused input pins should be tied to Vcc or GND.

#### Programmable Three-State Outputs

Each output has a three-state output buffer with three-state control. On combinatorial outputs, a product term controls the buffer, allowing enable and disable to be a function of any product of device inputs or output feedback. The combinatorial output provides a bidirectional I/O pin and may be configured as a dedicated input if the output buffer is always disabled. On registered outputs, an input pin controls the enabling of the three-state outputs.

#### Registers with Feedback

Registered outputs are provided for data storage and synchronization. Registers are composed of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock input.

#### **Register Preload**

The register on the AMD marked 16R8, 16R6, and 16R4 devices can be preloaded from the output pins to facilitate functional testing of complex state machine designs. This feature allows direct loading of arbitrary states, making it unnecessary to cycle through long test vector sequences to reach a desired state. In addition, transitions from illegal states can be verified by loading illegal states and observing proper recovery.

#### Power-Up Reset

All flip-flops power-up to a logic LOW for predictable system initialization. Outputs of the PAL16R8 Family will be HIGH due to the active-low outputs. The Vcc rise must be monotonic and the reset delay time is 1000 ns maximum.

#### **Security Fuse**

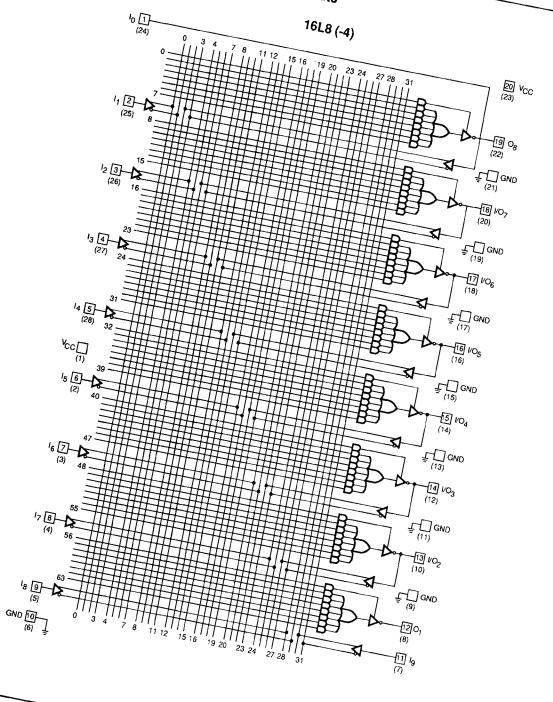
After programming and verification, a PAL16R8 Family design can be secured by programming the security fuse. Once programmed, this fuse defeats readback of the internal programmed pattern by a device programmer, securing proprietary designs from competitors. When the security fuse is programmed, the array will read as if every fuse is programmed.

#### **Quality and Testability**

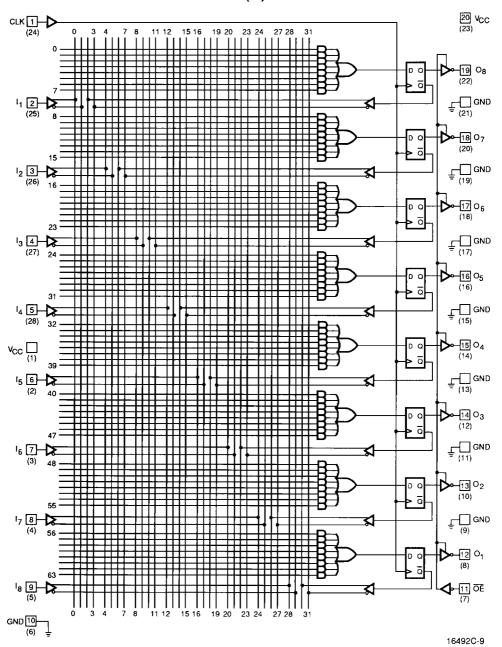
The PAL16R8 Family offers a very high level of built-in quality. Extra programmable fuses provide a means of verifying performance of all AC and DC parameters. In addition, this verifies complete programmability and functionality of the device to provide the highest programming yields and post-programming functional yields in the industry.

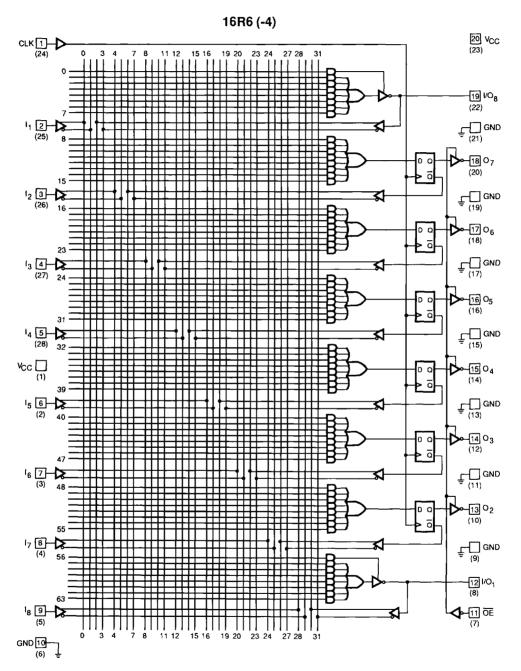
#### **Technology**

The PAL16R8-5, -7 and D/2 are fabricated with AMD's oxide isolated bipolar process. The array connections are formed with highly reliable PtSi fuses. The PAL16R8B, B-2, A and B-4 series are fabricated with AMD's advanced trench-isolated bipolar process. The array connections are formed with proven TiW fuses for reliable operation. These processes reduce parasitic capacitances and minimum geometries to provide higher performance.

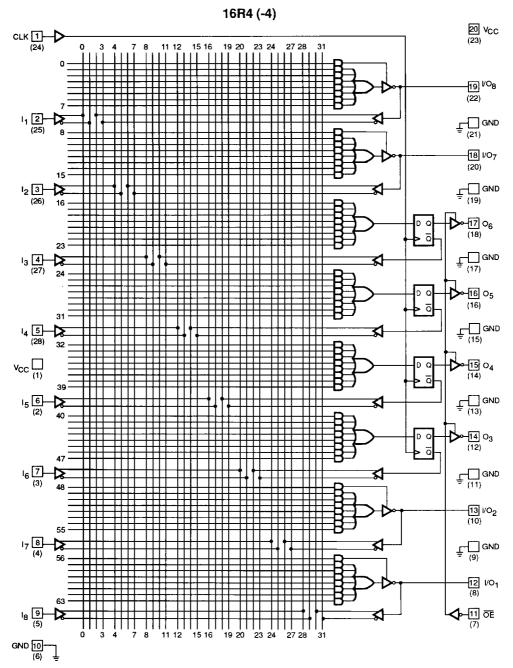


16R8 (-4)





16492C-10



16492C-11



Ambient Temperature with Power Applied ~65°C to +150°C
Storage Temperature55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to + 7.0 V
DC Input Voltage1.2 V to Vcc + 0.5 V
DC Input Current30 mA to + 5 mA
DC Output or I/O Pin
Voltage0.5 V to Vcc + 0.5 V
Static Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
VoH	Output HIGH Voltage	$I_{OH} = -3.2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		
Vol	Output LOW Voltage	I <sub>OL</sub> = 24 mA		0.5	٧
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	>
$V_{l}$	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min		-1.2	٧
l <sub>IH</sub>	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max (Note 2)		25	μА
I <sub>IL</sub>	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 2)		-250	μА
l <sub>i</sub>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mA
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max V <sub>IN</sub> ≈ V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> ≈ V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		~100	μА
lsc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> ≈ 0 V, Outputs Open (I <sub>OUT</sub> ≈ 0 mA) V <sub>CC</sub> = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of I<sub>IL</sub> and IOZL (or I<sub>IH</sub> and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	on	Test Condition	ıs	Тур	Unit
Cin	Input Capacitance	CLK, OE	V <sub>IN</sub> = 2.0 V	Vcc = 5.0 V	- 8 - 5	
Соит	Output Capacitance	· · · · · · · · · · · · · · · · · · ·	V <sub>OUT</sub> = 2.0 V	T <sub>A</sub> = 25°C f = 1 MHz	8	ρF

#### Note:

#### SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

					-5		-4		
Parameter Symbol	Parameter Description				Min (Note 3)	Max	Min (Note 3)	Max	Unit
tpo	Input or Feed Combinatoria		· · · · ·	16L8, 16R8, 16R4	1	5	1	4.5	ns
ts	Setup Time fi Feedback to				4.5		4.5		ns
t <sub>H</sub>	Hold Time				0		0		ns
tco	Clock to Outp	out			1	4.0	1	3.5	ns
tskewa	Skew Betwee Outputs (Note					1		0.5	ns
twL		Low		16R8, 16R6, 16R4	4	-	4		ns
tw <sub>H</sub>	Clock Width	HIGH		1014	4		4		ns
	Maximum	External Feedback	1/(ts + tco)	1	117		125		MHz
<b>fmax</b>	Frequency	Internal Feedback (fo	CNT)	1	125		125		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)	1	125		125		MHz
tpzx	OE to Output	Enable			1	6.5	1	6.5	ns
tpxz	OE to Output	ut Disable		1	1	5	1	5	ns
tea .	Input to Outp	ut Enable Using Control		461.0.4670	2	6.5	2	6.5	ns
ter	Input to Output Product Term	ut Disable Using Control		16L8, 16R6, 16R4	2	5	2	5	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for tpp, tco, tpzx, texz, tex, and ten are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Skew testing takes into account pattern and switching direction differences between outputs.
- 5. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied
Supply Voltage with Respect to Ground $-0.5$ V to + 7.0 V
DC Input Voltage1.2 V to + 7.0 V
DC Input Current30 mA to + 5 mA
DC Output or I/O Pin
Voltage0.5 V to Vcc + 0.5 V
Static Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Ambient Temperature (TA)
Operating in Free Air ..... 0°C to +75°C
Supply Voltage (Vcc)
with Respect to Ground ..... +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
V <sub>ОН</sub>	Output HIGH Voltage	$I_{OH} = -3.2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		٧
Vol	Output LOW Voltage	$I_{OL} = 24 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$		0.5	<b>&gt;</b>
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min		-1.2	>
lін	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max (Note 2)		25	μΑ
lıı	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 2)		-250	μΑ
<b>I</b> ı	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		-100	μА
lsc	Output Short-Circuit Current	V <sub>O∪T</sub> = 0.5 V, V <sub>CC</sub> = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc ≈ 5.0 V	5	ρF
Соит	Output Capacitance	Vout = 2.0 V	T <sub>A</sub> = 25°C f = 1 MHz	8	pr

#### Note:

 These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

#### **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Des	cription			Min (Note 3)	Max	Unit
	Input or Feedba	ck to		16L8, 16R6,	3_	7.5	
teo	Combinatorial C	Output	1 Output Switching	16R4	3	7	ns
ts	Setup Time fron	n Input or Feedback to	o Clack		7		ns
tн	Hold Time			7	0		ns
tco	Clock to Output				1	6.5	ns
tskew	Skew Between	Registered Outputs (N	egistered Outputs (Note 4)			1	ns
tw∟	Clack Width	LOW		16R4	5		ns
twn	- Cook Width	HIGH			5		ns
	Maximum	External Feedbac	k 1/(ts + tco)		74		MHz
fmax	Frequency	Internal Feedback	K (font)	1	100		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)	7	100		MHz
tpzx	OE to Output Er	E to Output Enable		7	1	8	ns
texz	OE to Output Di	sable		1	1	8	ns
tea .	Input to Output	nable Using Product Term Control		16L8, 16R6,	3	10	ns
ten	Input to Output I	Disable Using Produc	t Term Control	16R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for tPD, tCO, tPZX, tPXZ, tEA, and tER are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Skew is measured with all outputs switching in the same direction.
- 5. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.



Storage Temperature ..... -65°C to +150°C

Ambient Temperature with
Power Applied ..... -55°C to +125°C

Supply Voltage with
Respect to Ground ..... -0.5 V to + 7.0 V

DC Input Voltage ..... -1.5 V to + 5.5 V

DC Output or I/O Pin Voltage .... -0.5 V to + 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Static Discharge Voltage . . . . . . . . . . . . 2001 V

#### **OPERATING RANGES**

#### Commercial (C) Devices

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air . . . . . . . . 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground . . . . . +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -3.2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		٧
Vol	Output LOW Voltage	I <sub>OL</sub> = 24 mA		0.5	٧
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min		-1.5	V
lıн	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max (Note 2)		25	μA
I <sub>IL</sub>	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 2)		-250	μА
l <sub>i</sub>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		100	μА
ЮZH	Off-State Output Leakage Current HIGH	V <sub>OUT</sub> = 2.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		-100	μΑ
lsc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub> = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Condition	98	Тур	Unit
Cin	Input Capacitance	V <sub>IN</sub> = 2.0 V	Vcc = 5.0 V T <sub>A</sub> = 25°C	5	-F
Соит	Output Capacitance	V <sub>OUT</sub> = 2.0 V	f = 1 MHz	8	ρF

#### Note:

#### **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Des	cription			Min (Note 3)	Max	Unit
teo	Input or Feedbar Combinatorial O			16L8, 16R6, 16R4	3	10	ns
ts	Setup Time from	n Input or Feedback to Clo	ck		10	_	ns
tн	Hold Time				0		ns
tco	Clock to Output			]	3	7	ns
twL	Clock Width	LOW	LOW		8		ns
twn	1	HIGH		16R8, 16R6,	8		ns
	Maximum	External Feedback	1/(ts + tco)	16R4	58.8		MHz
†MAX	Frequency	Internal Feedback (fc	NT)	1	60		MHz
	(Note 4)	No Feedback	1/(tw+ + twL)	1	62.5		MHz
tezx	OE to Output Er	nable		1	2	10	ns
tpxz	OE to Output Di	sable		L	2	10	ns
tea	Input to Output I	Enable Using Product Term Control		16L8, 16R6,	3	10	ns
ten	Input to Output I	Disable Using Product Ter	m Control	16R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for t<sub>PD</sub>, t<sub>CO</sub>, t<sub>PZX</sub>, t<sub>EXZ</sub>, t<sub>EX</sub>, and t<sub>ER</sub> are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature .... -65°C to +150°C

Ambient Temperature with

Power Applied .... -55°C to +125°C

Supply Voltage with

Respect to Ground .... -0.5 V to +7.0 V

DC Input Voltage .... -1.5 V to Vcc + 0.5 V

DC Output or I/O Pin

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Voltage ..... -0.5 V to Vcc + 0.5 V

#### **OPERATING RANGES**

#### Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions		Min	Мах	Unit
V <sub>OH</sub>	Output HIGH Voltage	loн = -3.2 mA	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>CC</sub> = Min	2.4	_	٧
V <sub>OL</sub>	Output LOW Voltage	loL = 24 mA	VIN = VIH OF VIL		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Voltage for all Inpu	•	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	٧
Vı	input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> =	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min		-1.2	٧
I <sub>IH</sub>	Input HIGH Current	VIN = 2.4 V, Vcc =	Max (Note 2)		25	μА
l <sub>IL</sub>	Input LOW Current	VIN = 0.4 V, VCC =	Max (Note 2)		-250	μΑ
l <sub>1</sub>	Maximum Input Current	Vin = 5.5 V, Vcc =	Max		100	μА
lozh	Off-State Output Leakage Current HIGH	V <sub>OUT</sub> = 2.4 V, V <sub>CC</sub> V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (No			100	μА
lozL	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)			-100	μА
Isc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub>	= Max (Note 3)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lou <sub>T</sub> = 0 mA) V <sub>CC</sub> = Max			180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second.
   Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V <sub>IN</sub> = 2.0 V	Vcc = 5.0 V T <sub>A</sub> = 25°C	8	
Cout	Output Capacitance	V <sub>OUT</sub> = 2.0 V	f = 1 MHz	9	pF

#### Note:

#### SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	Parameter Description				Max	Unit
teo	Input or Feedba Combinatorial C			16L8, 16R6, 16R4		15	ns
ts	Setup Time from	n Input or Feedback to Clo	ck		15		ns
tH	Hold Time			1	0		ns
tco	Clock to Output	or Feedback	-	1		12	ns
twL	Clock Width	LOW	LOW		10		ns
twH		HIGH		1 16R8, 16R6, 16R4	10		ns
	Maximum	External Feedback	1/(ts + tco)		37		MHz
fmax	Frequency (Note 3)	No Feedback	1/(tw+ + twL)	1	50	-	MHz
tezx	OE to Output Er	nable		1		15	ns
texz	OE to Output Di	DE to Output Disable		1		15	ns
tEA	Input to Output Enable Using Product Term Control		16R8, 16R6,		15	ns	
ter	Input to Output I	Disable Using Product Ter	m Control	16R4		15	ns

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

<sup>2.</sup> See Switching Test Circuit for test conditions.

<sup>3.</sup> These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature .... -65°C to +150°C

Ambient Temperature with
Power Applied .... -55°C to +125°C

Supply Voltage with
Respect to Ground .... -0.5 V to +7.0 V

DC Input Voltage .... -1.5 V to Vcc + 0.5 V

DC Output or I/O Pin

Voltage .... -0.5 V to Vcc + 0.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -3.2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = \text{Min}$	2.4		>
Vol	Output LOW Voltage	lot = 24 mA		0.5	٧
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> = −18 mA, V <sub>CC</sub> = Min		-1.2	٧
l <sub>IH</sub>	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max (Note 2)		25	μΑ
lıL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 2)		-100	μ <b>Α</b>
l <sub>1</sub>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		100	μΑ
lozн	Off-State Output Leakage Current HIGH	V <sub>OUT</sub> = 2.7 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		100	μА
lozu	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		-100	μΑ
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max		90	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 2.0 V	Vcc ≈ 5.0 V	7	
			T <sub>A</sub> = 25°C		pF
Соит	Output Capacitance	V <sub>OUT</sub> = 2.0 V	f = 1 MHz	7	[

#### Note:

#### **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Des	Parameter Description			Min	Max	Unit
tpo	Input or Feedba Combinatorial C			16L8, 16R6, 16R4		25	ns
ts	Setup Time from	Input or Feedback to Clo	ck		25		ns
tн	Hold Time	-		7	0		ns
tco	Clock to Output					15	ns
twL	Clock Width	LOW		16R8, 16R6,	15		ns
twн		HIGH	HIGH		15		ns
	Maximum	External Feedback	1/(ts + tco)	16R4	25		MHz
fmax	Frequency	Internal Feedback (fc	NT)	1	28.5		MHz
	(Note 4)	No Feedback	1/(tw+ + twL)	]	33		MHz
tezx	OE to Output Er	nable		]		20	ns
texz	OE to Output Di	DE to Output Disable		]		20	ns
t <sub>ea</sub>	Input to Output Enable Using Product Term Control		16R8, 16R6,		25	ns	
ter	Input to Output I	Disable Using Product Ter	m Control	16R4	-	25	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Calculated from measured fMAX internal.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	–55°C to +125°C
Supply Voltage with Respect to Ground	0.5 V to + 7.0 V
DC Input Voltage	1.5 V to Vcc + 0.5 V
DC Output or I/O Pin	
Voltage	0.5.V to Voc. + 0.5.V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Ambient Temperature (T <sub>A</sub> ) Operating in Free Air	0°C to +75°C
Supply Voltage (Vcc) with Respect to Ground +4.75	5 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Descript	ion	Test Condition	s	Min	Max	Unit
Voн	Output HIGH Voltage	,	loн = -3.2 mA	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>CC</sub> = <b>Min</b>	2.4		٧
VoL	Output LOW Voltage		loL = 24 mA	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>CC</sub> = Min		0.5	V
VIH	Input HIGH Voltage	Input HIGH Voltage		ut Logical HIGH nputs (Note 1)	2.0		٧
VIL	Input LOW Voltage		Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	٧
Vi	Input Clamp Voltage		I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min			-1.2	V
l <sub>H</sub>	Input HIGH Current		V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max (Note 2)			25	μА
l <sub>IL</sub>	Input LOW Current		V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 2)			-250	μΑ
l <sub>l</sub>	Maximum Input Curre	ent	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max			100	μА
lozн	Off-State Output Lea	kage	V <sub>OUT</sub> = 2.7 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)			100	μА
lozL	Off-State Output Leal Current LOW	kage	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)			-100	μA
lsc	Output Short-Circuit (	Current	Vout = 0.5 V, Vcc = Max (Note 3)		-30	-130	mA
lcc	Supply Current	16L8 16R8/6/4	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max			155 180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. VCC = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V <sub>IN</sub> = 2.0 V	$V_{CC} = 5.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$	7	
Соит	Output Capacitance	V <sub>OUT</sub> = 2.0 V	f = 1 MHz	7	ρF

#### Note:

#### **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Description					Max	Unit
teo	Input or Feedba Combinatorial C					25	ns
ts	Setup Time from	n Input or Feedback to Clo	ock		25		ns
tн	Hold Time				0		ns
tco	Clock to Output					15	ns
twL	Clock Width	LOW			15		ns
twн		HIGH	HIGH		15		ns
	Maximum	External Feedback	1/(ts + tco)	16R8, 16R6, 16R4	25		MHz
fmax	Frequency	Internal Feedback (fc	NT)	1	28.5		MHz
	(Note 4)	No Feedback	1/(tw+ + twL)	1	33		MHz
tezx	OE to Output E	nable		1		20	ns
texz	OE to Output Disable			1		20	ns
tea	Input to Output	Enable Using Product Terr	m Control	16R8, 16R6,		25	ns
ten	Input to Output	Disable Using Product Ter	m Control	16R4		25	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Calculated from measured fMAX internal.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



7100010 III III II III II II II II II II II II
Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied
Supply Voltage with Respect to Ground0.5 V to +7.0 V
DC Input Voltage1.5 V to +5.5 V
DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Ambient Temperature (T <sub>A</sub> ) Operating in Free Air	0°C to +75°C
Supply Voltage (Vcc)	±4 75 V to ±5 25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -1 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		>
Vol	Output LOW Voltage	I <sub>OL</sub> = 8 mA		0.5	>
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		>
VıL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vi	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, Vcc = Min		-1.5	V
Ін	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max (Note 2)		25	μА
I <sub>iL</sub>	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 2)		-250	μА
11	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		100	μА
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max Vin = Vihor Vil (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		-100	μΑ
lsc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub> = Max (Note 3)	-30	-250	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (I <sub>OUT</sub> = 0 mA) V <sub>CC</sub> = Max		55	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second.
   Vout = 0.5 V as been chosen to avoid test problems caused by tester ground degradation.



#### **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)**

Parameter Symbol	Parameter Des	Parameter Description					Unit
tpp	Input or Feedback to Combinatorial Output			16L8, 16R6, 16R4	_	35	ns
ts	Setup Time from Input or Feedback to Clock				35		ns
tн	Hold Time	old Time			0		ns
tco	Clock to Output	or Feedback	or Feedback			25	ns
twL	Clock Width	LOW		16R4	25		ns
twn	1	HIGH		1	25		ns
f <sub>MAX</sub>	Maximum Frequency	External Feedback	1/(ts + tco)	] [	16		MHz
INIOA	(Note 2)	No Feedback	1/(tw+ + twL)		20		MHz
tezx	OE to Output Er	nable	-	1		25	ns
texz	OE to Output Disable			1		25	ns
tea .	Input to Output Enable Using Product Term Control			16L8, 16R6,		35	ns
tea	Input to Output I	Disable Using Product Ter	m Control	16R4		35	ns

- 1. See Switching Test Circuit for test conditions.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

# OPERATING RANGES Military (M) Devices (Note 1)

Ambient Temperature (T <sub>A</sub> ) Operating in Free Air5	5°C Min
Operating Case (Tc) Temperature	5°C Max
Supply Voltage (Vcc) with Respect to Ground +4.50 V to	+5.50 V

#### Note:

 Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = \text{Min}$	2.4		V
Vol	Output LOW Voltage	$I_{OL} = 12 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$		0.5	V
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		V
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	V
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min		-1.2	٧
I <sub>IH</sub>	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max (Note 4)	T	25	μА
lıL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 4)		-250	μА
lı	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mA
Іохн	Off-State Output Leakage Current HIGH	$V_{OUT} = 2.7 \text{ V}, V_{CC} = \text{Max}$ $V_{IN} = V_{IH} \text{ or } V_{IL} \text{ (Note 4)}$		100	μА
lozL	Off-State Output Leakage Current LOW	$V_{OUT} = 0.4 \text{ V}, V_{CC} = \text{Max}$ $V_{IN} \approx V_{IH} \text{ or } V_{IL} \text{ (Note 4)}$		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> ≈ 0 V, Outputs Open (I <sub>OUT</sub> = 0 mA) Vcc = Max		200	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Descrip	tion	Test Conditions		Тур	Unit
Cin	Input Capacitance	Corner Pins Middle Pins	V <sub>IN</sub> = 2.0 V	V <sub>CC</sub> = 5.0 V T <sub>A</sub> = 25°C	10 5	pF
Соит	Output Capacitance		V <sub>OUT</sub> = 2.0 V	f = 1 MHz	9	

#### Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

					-10		-12		
Parameter Symbol	Parameter De	escription			Min (Note 3)	Max	Min (Note 3)	Max	Unit
ten	Input or Feedback to Combinatorial Output			16L8, 16R6, 16R4	3	10	3	12	ns
ts	Setup Time fro	om Input or Feedback t	o Clock		10		10		ns
tн	Hold Time			]	0		0		ns
tco	Clock to Outpo	ut		1	3	9	3	11	ns
tskew	Skew Between	Registered Outputs (Note 4)		1		1		1	ns
twL		LOW		16R8,	8		8		ns
twн	Clock Width	HIGH		16R6, 16R4	8		8		ns
	Maximum	External Feedback	1/(ts + tco)	1	52.6		47.6		MHz
fmax	Frequency (Note 5)	Internal Feedback (fo	CNT)	1	60.6		60.6		MHz
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	No Feedback	1/(tw+ + twL)	1	62.5		62.5		MHz
tezx	OE to Output	Enable (Note 5)	-		3	10	3	12	ns
texz	OE to Output Disable (Note 5)		1	3	10	3	12	ns	
tea		out to Output Enable Using Product rm Control (Note 5) out to Output Disable Using Product rm Control (Note 5)		16L8, 16R6,	3	10	3	12	ns
ter				16R4	3	10	3	12	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MiL-STD-883, Method 5005, unless otherwise noted.
- 3. Minimum value for tpD, tco, tpzx, tpxz, teA, and teR parameters should be used for simulation purposes only and are not tested.
- 4. Skew is measured with all outputs switching in the same direction.
- 5. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.



Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied –55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to +7.0 V
DC Input Voltage1.5 V to +5.5 V
DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

### OPERATING RANGES Military (M) Devices (Note 1)

minus y (m, zeriese (meter)
Ambient Temperature (Ta) Operating in Free Air55°C Min
Operating Case (Tc) Temperature
Supply Voltage (Vcc) with Respect to Ground +4.50 V to +5.50 V

#### Note:

1. Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
V <sub>он</sub>	Output HIGH Voltage	$I_{OH} = -2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} \approx Min$	2.4		٧
Vol	Output LOW Voltage	$I_{OL} = 12 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} \approx \text{Min}$		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> ≈ −18 mA, V <sub>CC</sub> = Min		-1.5	٧
Ін	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max (Note 4)		25	μА
lı.	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 4)		-250	μА
ħ	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mA
ЮZН	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		100	μΑ
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		-100	μА
Isc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub> = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (Iout = 0 mA) Vcc = Max		180	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

#### \_\_\_\_

#### **CAPACITANCE** (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V <sub>IN</sub> = 2.0 V	V <sub>CC</sub> = 5.0 V T <sub>A</sub> = 25°C	9	
Соит	Output Capacitance	V <sub>O</sub> υτ = 2.0 V	f = 1 MHz	10	pF

#### Note:

#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

Parameter Symbol	Parameter Description				Min	Max	Unit
ted	Input or Feedba Combinatorial O		16L8, 16R6, 16R4		20	ns	
ts	Setup Time from	n Input or Feedback to Clo	ock		20		ns
tн	Hold Time			0		ns	
tco	Clock to Output	or Feedback				15	ns
twL	Clock Width	LOW			12		ns
twн	Clock Wiath	HIGH		16L8, 16R6,	12		ns
fmax	Maximum	External Feedback	1/(ts + tco)	16R4	28.5		MHz
	Frequency (Note 3)	No Feedback	1/(tw+ + twL)		41.6		MHz
tezx	OE to Output Er	nable (Note 4)				20	ns
texz	OE to Output Disable (Note 4)					20	ns
tea	1 '	t to Output Enable Using Product n Control (Note 4)				25	ns
ten	Input to Output Disable Using Product Term Control (Note 4)			16R4		20	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



, 120012 1 1 1 1 1 1 1.
Storage Temperature $$ $-65^{\circ}$ C to $+150^{\circ}$ C
Ambient Temperature with Power Applied55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to +7.0 V
DC Input Voltage1.5 V to +5.5 V
DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

#### **OPERATING RANGES**

#### Military (M) Devices (Note 1)

Ambient Temperature (Ta) Operating in Free Air55°C Min
Operating Case (Tc) Temperature
Supply Voltage (Vcc) with Respect to Ground +4.50 V to +5.50 V

#### Note:

1. Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		٧
Vol	Output LOW Voltage	lot = 12 mA		0.5	٧
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		V
VıL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min		-1.5	V
lн	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max (Note 4)		25	μА
liL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 4)		-250	μ <b>A</b>
l <sub>i</sub>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mΑ
ЮZH	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		100	μА
loz∟	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		-100	μΑ
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (I <sub>OUT</sub> = 0 mA) V <sub>CC</sub> = Max		90	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V <sub>IN</sub> ≈ 2.0 V	Vcc = 5.0 V T <sub>A</sub> = 25°C	7	ρF
Соит	Output Capacitance	Vout = 2.0 V	f = 1 MHz	7	l br

#### Note:

#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

Parameter Symbol	Parameter Description				Min	Max	Unit
t <sub>PD</sub>	Input or Feedba Combinatorial C		16L8, 16R6, 16R4		30	ns	
ts	Setup Time from	n Input or Feedback to Clo	ock		30		ns
t <sub>H</sub>	Hold Time			] [	0		ns
tco	Clock to Output	or Feedback		·-	20	ns	
twL	Clock Width	LOW		16L8, 16R6,	20		ns
twn		HIGH		16R4	20		ns
	Maximum	External Feedback	1/(ts + tco)		20	]	MHz
fmax ,	Frequency (Note 3)	No Feedback	1/(tw+ + twL)		25		MHz
tpzx	OE to Output Er	nable (Note 4)				25	ns
texz	OE to Output Disable (Note 4)					25	ns
tea	Input to Output Enable Using Product Term Control (Note 4)			16L8, 16R6,		30	ns
ter	Input to Output Disable Using Product Term Control (Note 4)			16R4		30	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



ADOCEOTE MAXIMUM HATINGS
Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied –55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to + 7.0 V
DC Input Voltage1.5 V to + 5.5 V
DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

# OPERATING RANGES Military (M) Devices (Note 1)

Ambient Temperature (TA)	
Operating in Free Air	-55°C Min

Supply Voltage (Vcc) with Respect to Ground ...... +4.50 V to +5.50 V

#### Note:

 Military products are tested at T<sub>C</sub> = +25°C, +125°C, and -55°C, per MIL-STD-883.

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = \text{Min}$	2.4		<b>&gt;</b>
Vol	Output LOW Voltage	$I_{OL} = 12 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	l <sub>IN</sub> = −18 mA, V <sub>CC</sub> = Min		-1.5	٧
lн	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max (Note 4)		25	μА
I <sub>I</sub> L	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 4)		-250	μА
lı —	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		100	μА
lozL	Off-State Output Leakage Current LOW	V <sub>OUT</sub> = 0.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		-100	μА
Isc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub> = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max		180	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур_	Unit
Cin	Input Capacitance	V <sub>IN</sub> = 2.0 V	V <sub>cc</sub> = 5.0 V T <sub>A</sub> = 25°C	7	
Соит	Output Capacitance	V <sub>OUT</sub> = 2.0 V	f = 1 MHz	7	pF

#### Note:

#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

Parameter Symbol	Parameter Des	cription		Min	Max	Unit		
<b>t</b> PD	Input or Feedba Combinatorial C			16L8, 16R6, 16R4		30	ns	
ts	Setup Time from	n Input or Feedback to Clo	ock		30		ns	
tн	Hold Time			1	0		ns	
tco	Clock to Output	or Feedback	Feedback			20	ns	
tw.	Clock Width	LOW		16L8, 16R6, 16R4	]	20		ns
twн	1	HIGH			20		ns	
fwax	Maximum Frequency	External Feedback	1/(ts + tco)		20		MHz	
IMAX	(Note 3)	No Feedback	1/(tw+ + twL)		25		MHz	
tezx	OE to Output Er	nable (Note 4)	•	1		25	ns	
texz	OE to Output Di	sable (Note 4)		]		25	ns	
tea	Input to Output Term Control (N	Enable Using Product lote 4)	16L8, 16R6,		30	ns		
t∈n	Input to Output Term Control (N	Disable Using Product lote 4)		16R4		30	ns	

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to + 7.0 V
DC Input Voltage
DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

#### **OPERATING RANGES**

#### Military (M) Devices (Note 1)

Ambient Temperature (Ta) Operating in Free Air
Operating Case (Tc) Temperature
Supply Voltage (Vcc) with Respect to Ground +4.50 V to +5.50 V

#### Note:

1. Military products are tested at  $T_C = +25^{\circ}C$ ,  $+125^{\circ}C$ , and  $-55^{\circ}C$ , per MIL-STD-883.

Operating ranges define those limits between which the functionality of the device is guaranteed.

### DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
V <sub>OH</sub>	Output HIGH Voltage	$I_{OH} = -1 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		٧
Vol	Output LOW Voltage	$I_{OL} = 4 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	$I_{IN} = -18$ mA, $V_{CC} = Min$		-1.5	٧
I <sub>IH</sub>	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max (Note 4)		25	μА
l <sub>IL</sub>	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max (Note 4)		-250	μА
lı	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max		1	mA
Іохн	Off-State Output Leakage Current HIGH	V <sub>OUT</sub> = 2.4 V, V <sub>CC</sub> = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		100	μА
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 4)		-100	μА
Isc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub> = Max (Note 5)	-30	-250	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) Vcc = Max		55	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

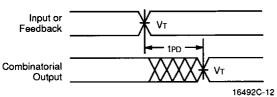


#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 1)**

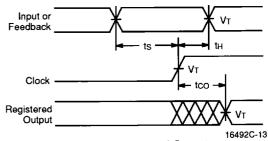
Parameter Symbol	Parameter Des		Min	Max	Unit		
<b>t</b> PD	Input or Feedba Combinatorial O		· 	16L8, 16R6, 16R4		50	ns
ts	Setup Time from	n Input or Feedback to Clo	ock		50		ns
tн	Hold Time				0		ns
tco	Clock to Output	or Feedback				25	ns
tw∟	Clock Width	LOW			25	•	ns
twn		HIGH		16L8, 16R6,	25		ns
fmax	Maximum Frequency	External Feedback	1/(ts + tco)	- 16R4	13.3		MHz
IMAA	(Note 2)	No Feedback	1/(tw+ + twL)		20		MHz
tezx	OE to Output Er	nable (Note 3)				25	ns
texz	OE to Output Disable (Note 3)					25	ns
tea	1 '	Input to Output Enable Using Product Term Control (Note 3)				45	ns
ten	Input to Output I Term Control (N	o Output Disable Using Product				45	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

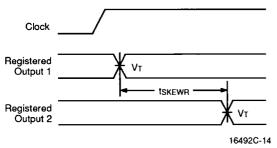
#### **SWITCHING WAVEFORMS**



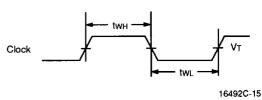
Combinatorial Output



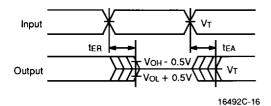
**Registered Output** 



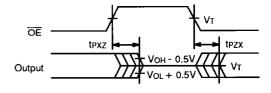
**Registered Output Skew** 



Clock Width



Input to Output Disable/Enable



0E to Output Disable/Enable

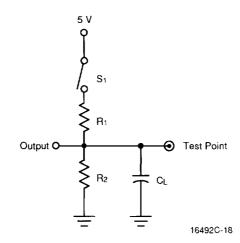
- 1.  $V_T = 1.5 V$
- 2. Input pulse amplitude 0 V to 3.0 V
- 3. Input rise and fall times 2 ns-3 ns typical.

#### **KEY TO SWITCHING WAVEFORMS**

WAVEFORM	INPUTS	OUTPUTS
	Must be Steady	Will be Steady
	May Change from H to L	Will be Changing from H to L
	May Change from L to H	Will be Changing from L to H
	Don't Care, Any Change Permitted	Changing, State Unknown
<b>&gt;&gt;</b> -≪<	Does Not Apply	Center Line is High- Impedance "Off" State

KS000010-PAL

#### **SWITCHING TEST CIRCUIT**

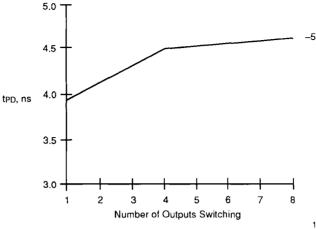


			Com	Commercial		itary	Measured
Specification	S <sub>1</sub>	CL	R <sub>1</sub>	R <sub>2</sub>	R <sub>1</sub>	R <sub>2</sub>	Output Value
tpo, tco	Closed		All but B-4:	All but B-4:	All but B-4:	All but B-4:	1.5 V
tpzx, tea	$Z \rightarrow H$ : Open $Z \rightarrow L$ : Closed	50 pF	200 Ω	390 Ω	390 Ω	750 Ω	
texz, ter	H → Z: Open L → Z: Closed	5 pF	B-4: 800 Ω	B-4: 1.56 kΩ	B-4: 800 Ω	B-4: 1.56 kΩ	H → Z: V <sub>OH</sub> − 0.5 V L → Z: V <sub>OL</sub> + 0.5 V



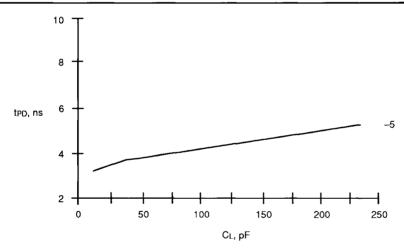
#### **MEASURED SWITCHING CHARACTERISTICS for the PAL16R8-5**

V<sub>CC</sub> = 4.75 V, T<sub>A</sub> = 75°C (Note 1)



16492C-19

tPD vs. Number of Outputs Switching



16492C-20

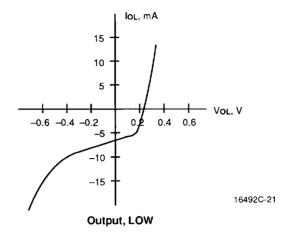
tpD vs. Load Capacitance Vcc = 5.25 V, TA = 25°C

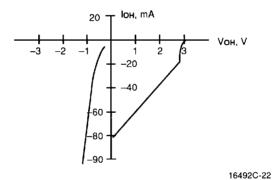
#### Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tpp may be affected.

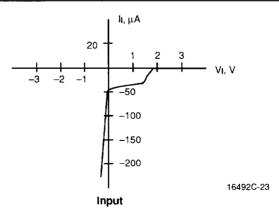
#### **CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS for the PAL16R8-4/5**

Vcc = 5.0 V, TA = 25°C



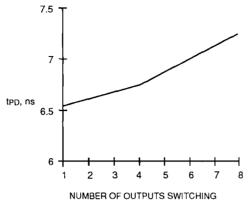


Output, HIGH



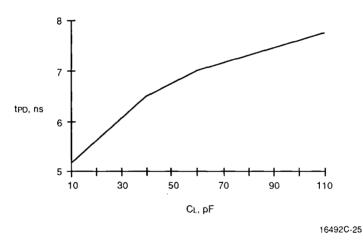
#### **MEASURED SWITCHING CHARACTERISTICS for the PAL16R8-7**

Vcc = 4.75 V, T<sub>A</sub> = 75°C (Note 1)



16492C-24

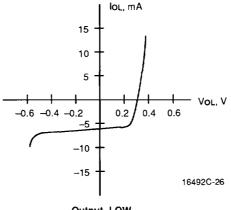
tpp vs. Number of Outputs Switching



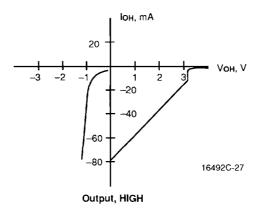
tpp vs. Load Capacitance

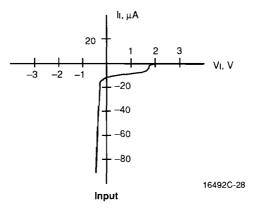
#### Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tpp may be affected.

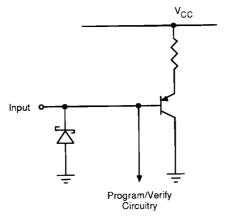


Output, LOW



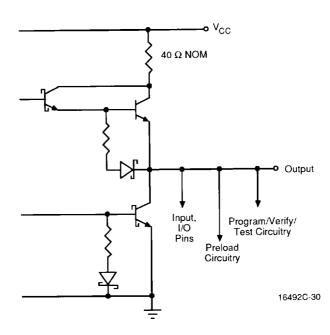


### INPUT/OUTPUT EQUIVALENT SCHEMATICS



16492C-29

Typical Input



**Typical Output** 

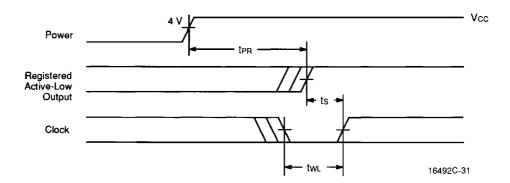
#### **POWER-UP RESET**

The power-up reset feature ensures that all flip-flops will be reset to LOW after the device has been powered up. The output state will be HIGH due to the inverting output buffer. This feature is valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the wide range of ways Vcc

can rise to its steady state, two conditions are required to ensure a valid power-up reset. These conditions are:

- The Vcc rise must be monotonic.
- Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Description	Max	Unit
ter	Power-Up Reset Time	1000	กร
ts	Input or Feedback Setup Time	See S	witching
twL	Clock Width LOW		cteristics



**Power-Up Reset Waveform**